## MMBF0201NL, MVMBF0201NL

# <u>MOSFET</u> – N-Channel, SOT-23

## 300 mA, 20 V

These miniature surface mount MOSFETs low  $R_{DS(on)}$  assure minimal power loss and conserve energy, making these devices ideal for use in small power management circuitry. Typical applications are dc-dc converters, power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

#### Features

- Low R<sub>DS(on)</sub> Provides Higher Efficiency and Extends Battery Life
- Miniature SOT-23 Surface Mount Package Saves Board Space
- MVMBF Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable\*
- These Devices are Pb-Free and are RoHS Compliant

#### **MAXIMUM RATINGS** ( $T_J = 25^{\circ}C$ unless otherwise noted)

		,	
Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>	20	Vdc
Gate-to-Source Voltage - Continuous	V <sub>GS</sub>	± 20	Vdc
Drain Current – Continuous @ T <sub>A</sub> = 25°C – Continuous @ T <sub>A</sub> = 70°C – Pulsed Drain Current (t <sub>p</sub> ≤ 10 μs)	I <sub>D</sub> ID I <sub>DM</sub>	300 240 750	mAdc
Total Power Dissipation @ $T_A = 25^{\circ}C$	PD	225	mW
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	– 55 to 150	°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	ΤL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

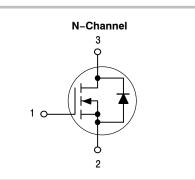


### **ON Semiconductor®**

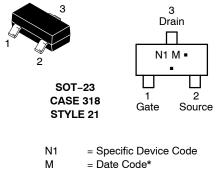
www.onsemi.com

## 300 mAMPS - 20 VOLTS

 $R_{DS(on)} = 1 \Omega$ 



MARKING DIAGRAM AND PIN ASSIGNMENT



= Pb-Free Package

(Note: Microdot may be in either location) \*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMBF0201NLT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
MVMBF0201NLT1G*	SOT-23 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## MMBF0201NL, MVMBF0201NL

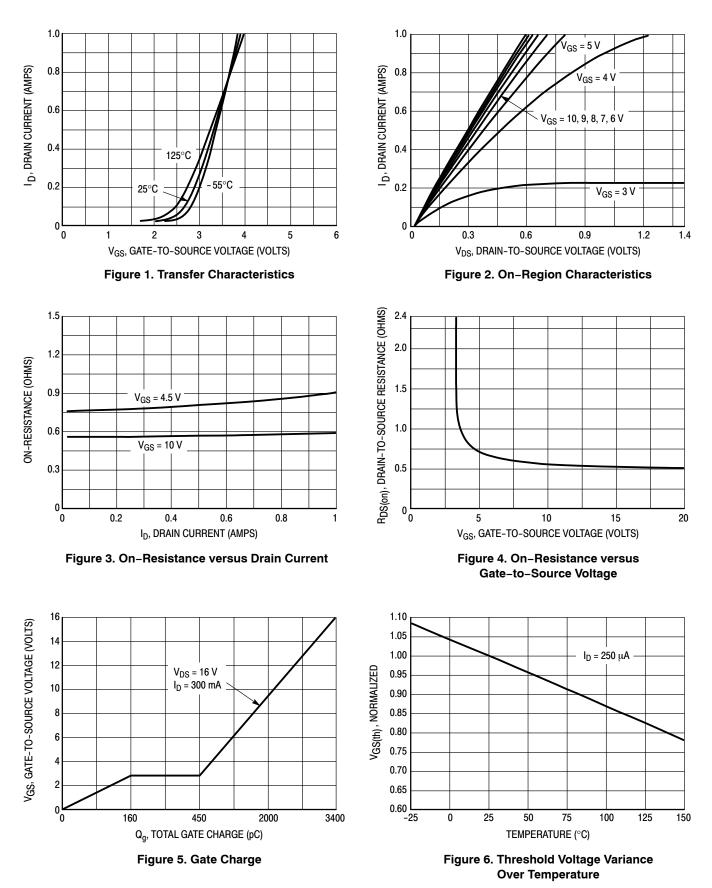
#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Char	acteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS				•		
Drain-to-Source Breakdown Voltage ( $V_{GS}$ = 0 Vdc, $I_D$ = 10 $\mu$ A)	,	V <sub>(BR)DSS</sub>	20	-	_	Vdc
Zero Gate Voltage Drain Current ( $V_{DS}$ = 16 Vdc, $V_{GS}$ = 0 Vdc) ( $V_{DS}$ = 16 Vdc, $V_{GS}$ = 0 Vdc, $T_J$ =	- 125°C)	I <sub>DSS</sub>			1.0 10	μAdc
Gate-Body Leakage Current ( $V_{GS} = \pm 20$ Vdc, $V_{DS} = 0$ )		I <sub>GSS</sub>	-	-	±100	nAdc
ON CHARACTERISTICS (Note 1)		-	1			•
Gate Threshold Voltage ( $V_{DS} = V_{GS}$ , $I_D = 250 \ \mu Adc$ )		V <sub>GS(th)</sub>	1.0	1.7	2.4	Vdc
$\begin{array}{l} \mbox{Static Drain-to-Source On-Resistar} \\ (V_{GS} = 10 \mbox{ Vdc}, \mbox{ I}_{D} = 300 \mbox{ mAdc}) \\ (V_{GS} = 4.5 \mbox{ Vdc}, \mbox{ I}_{D} = 100 \mbox{ mAdc}) \end{array}$	ce	r <sub>DS(on)</sub>		0.75 1.0	1.0 1.4	Ω
Forward Transconductance ( $V_{DS} = 1$	0 Vdc, I <sub>D</sub> = 200 mAdc)	9 <sub>FS</sub>	-	450	-	mMhos
DYNAMIC CHARACTERISTICS		-				
Input Capacitance	(V <sub>DS</sub> = 5.0 V)	C <sub>iss</sub>	-	45	-	pF
Output Capacitance	(V <sub>DS</sub> = 5.0 V)	C <sub>oss</sub>	-	25	-	
Transfer Capacitance	(V <sub>DG</sub> = 5.0 V)	C <sub>rss</sub>	-	5.0	-	
SWITCHING CHARACTERISTICS (	Note 2)	-				
Turn-On Delay Time	$(V_{DD}$ = 15 Vdc, I <sub>D</sub> = 300 mAdc, R <sub>L</sub> = 50 $\Omega$ )	t <sub>d(on)</sub>	-	2.5	_	ns
Rise Time		t <sub>r</sub>	-	2.5	-	
Turn-Off Delay Time		t <sub>d(off)</sub>	-	15	_	
Fall Time		t <sub>f</sub>	-	0.8	_	
Gate Charge (See Figure 5)		Q <sub>T</sub>	-	1400	-	рС
SOURCE-DRAIN DIODE CHARACT	TERISTICS	•	•	•		•
Continuous Current		۱ <sub>S</sub>	-	-	0.3	А
Pulsed Current		I <sub>SM</sub>	-	-	0.75	
Forward Voltage (Note 2)		V <sub>SD</sub>	-	0.85	-	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
1. Pulse Test: Pulse Width ≤ 300 µs, Duty Cycle ≤ 2%.
2. Switching characteristics are independent of operating junction temperature.

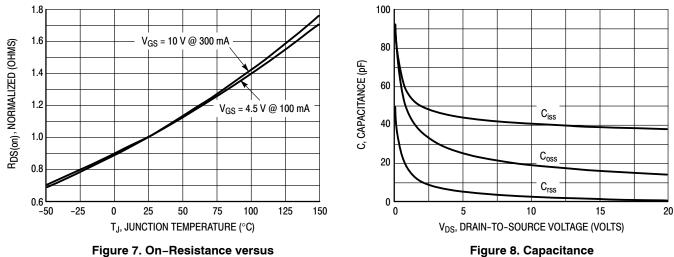
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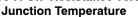
### **TYPICAL ELECTRICAL CHARACTERISTICS**



## MMBF0201NL, MVMBF0201NL

### **TYPICAL ELECTRICAL CHARACTERISTICS**







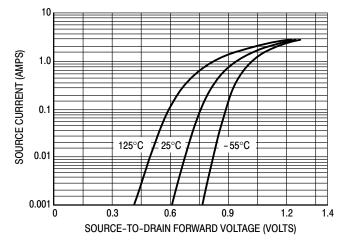


Figure 9. Source-to-Drain Forward Voltage versus Continuous Current (I<sub>S</sub>)





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